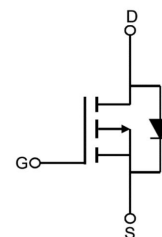
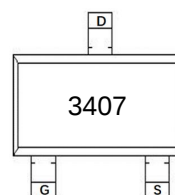


Feature

- -30V, -4.1A
 $R_{DS(ON)} < 52\text{ m}\Omega @ V_{GS} = -10V$ TYP=38 m Ω
 $R_{DS(ON)} < 62\text{ m}\Omega @ V_{GS} = -4.5V$ TYP=55 m Ω
- Advanced Trench Technology
- Excellent RDS(ON) and Low Gate Charge
- Lead free product is acquired



Schematic Diagram



Marking and pin Assignment

Application

- PWM Applications
- Load Switch
- Power Management

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity (PCS)
3407	AP3407	SOT-23	-	-	3000

ABSOLUTE MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current ($T_C = 25^\circ\text{C}$)	I_D	-4.1	A
Continuous Drain Current ($T_A = 100^\circ\text{C}$)	I_D	-2.7	A
Pulsed Drain Current ⁽¹⁾	I_{DM}	-16.4	A
Power Dissipation	P_D	1.4	W
Thermal Resistance from Junction to Ambient ⁽²⁾	$R_{\theta JA}$	89	$^\circ\text{C/W}$
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55~ +150	$^\circ\text{C}$

Notes:

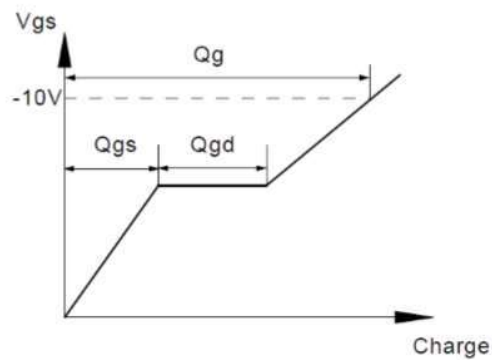
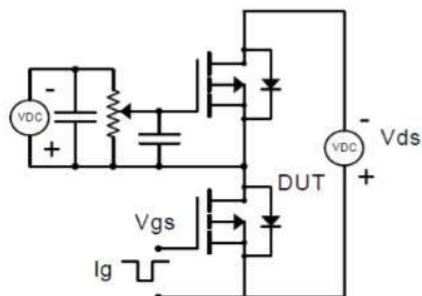
- 1) Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature
- 2) The value of $R_{\theta JA}$ Mounted on FR4 Board (25.4mm*25.4mm*t1.6mm) With 2oz Copper $T_A = 25^\circ\text{C}$

MOSFET ELECTRICAL CHARACTERISTICS($T_J=25^{\circ}\text{C}$ unless otherwise noted)

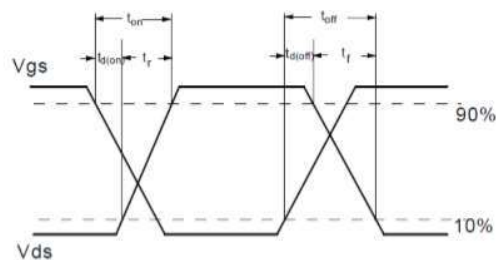
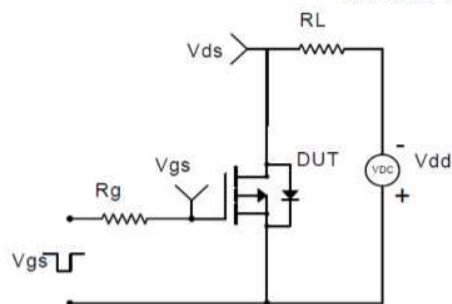
Parameter	Symbol	Test Condition	Min	Type	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =-250μA	-30	-	-	V
Zero gate voltage drain current	I _{DSS}	V _{DS} =-30V, V _{GS} = 0V	-	-	-1	μA
Gate-body leakage current	I _{GSS}	V _{GS} =±20V,V _{DS} = 0V	-	-	±100	nA
Gate threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-1.0	-1.5	-2.5	V
Drain-source on-resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-4A	-	38	52	mΩ
		V _{GS} =-4.5V, I _D =-3A	-	55	62	
Dynamic characteristics						
Input Capacitance	C _{iss}	V _{DS} =-15V, V _{GS} =0V, f =1MHz	-	580	-	pF
Output Capacitance	C _{oss}		-	98	-	
Reverse Transfer Capacitance	C _{rss}		-	74	-	
Switching characteristics						
Turn-on delay time	t _{d(on)}	V _{DD} =-15V, I _D =-1A, V _{GS} =-10V, R _G =2.5Ω	-	7	-	ns
Turn-on rise time	t _r		-	4	-	
Turn-off delay time	t _{d(off)}		-	18	-	
Turn-off fall time	t _f		-	13	-	
Total Gate Charge	Qg	V _{DS} =-15V, I _D =-4.1A, V _{GS} =-10V	-	11	-	nC
Gate-Source Charge	Qgs		-	1.9	-	
Gate-Drain Charge	Qgd		-	2	-	
Source-Drain Diode characteristics						
Diode Forward voltage	V _{DS}	V _{GS} =0V, I _S =-4.1A	-	-0.8	-1.2	V
Diode Forward current	I _S		-	-	-4.1	A

Test Circuit & Waveform

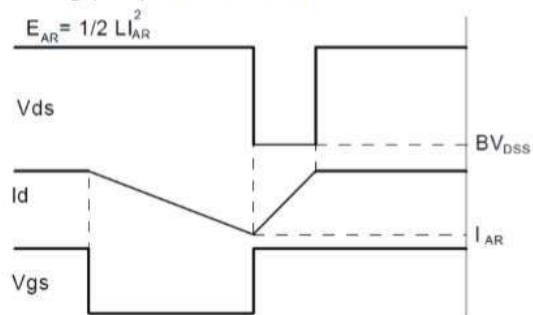
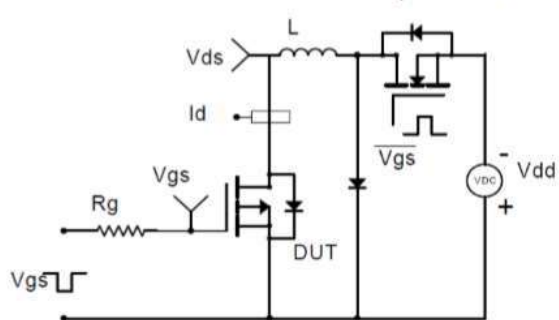
Gate Charge Test Circuit & Waveform



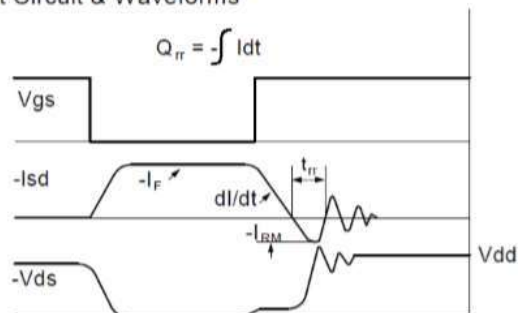
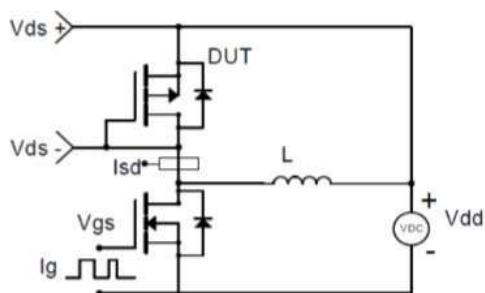
Resistive Switching Test Circuit & Waveforms



Unclamped Inductive Switching (UIS) Test Circuit & Waveforms



Diode Recovery Test Circuit & Waveforms



Typical Performance Characteristics

Figure1: Output Characteristics

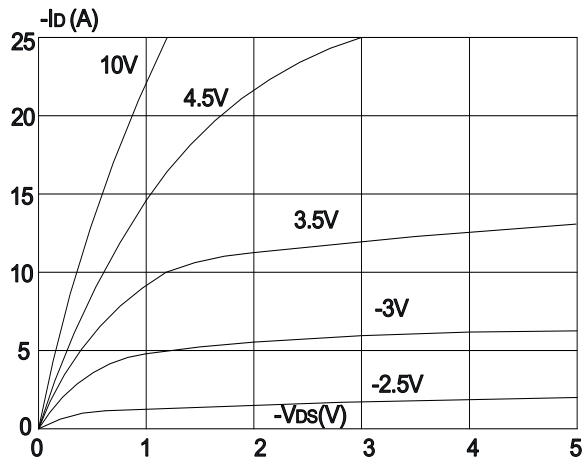


Figure 2: Typical Transfer Characteristics

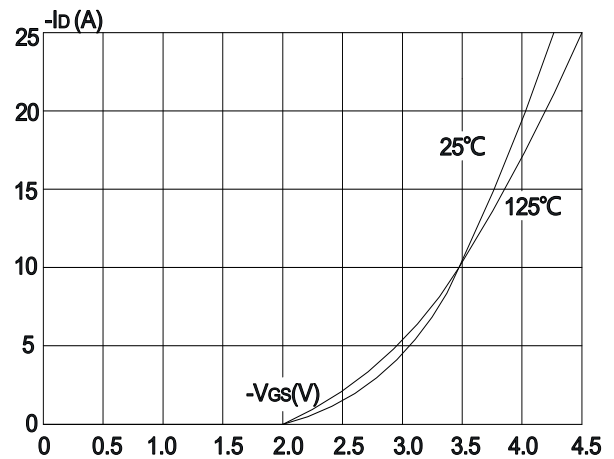


Figure 3: On-resistance vs. Drain Current

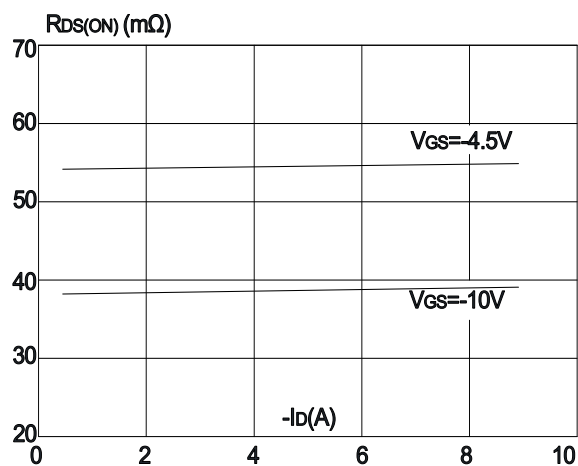


Figure 4: Body Diode Characteristics

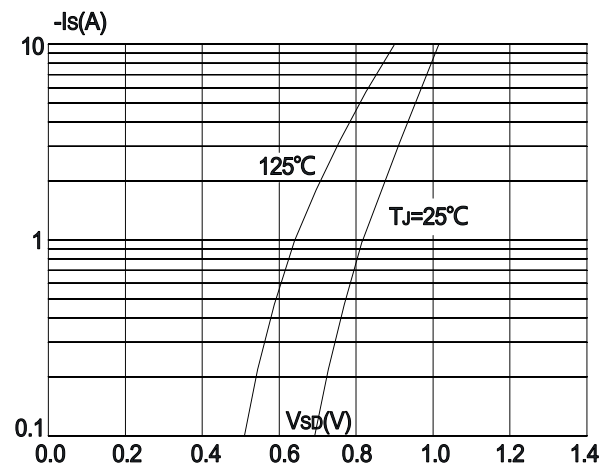


Figure 5: Gate Charge Characteristics

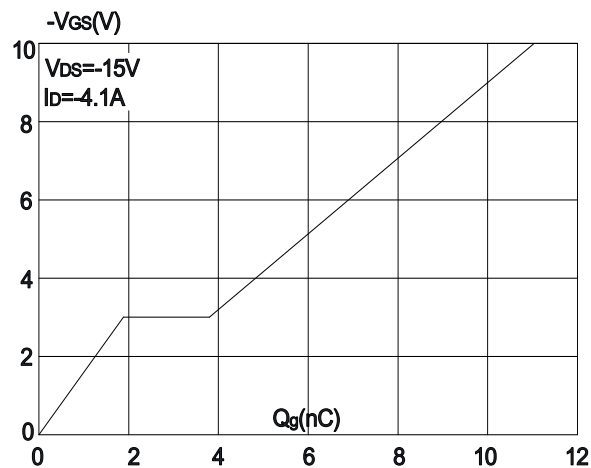
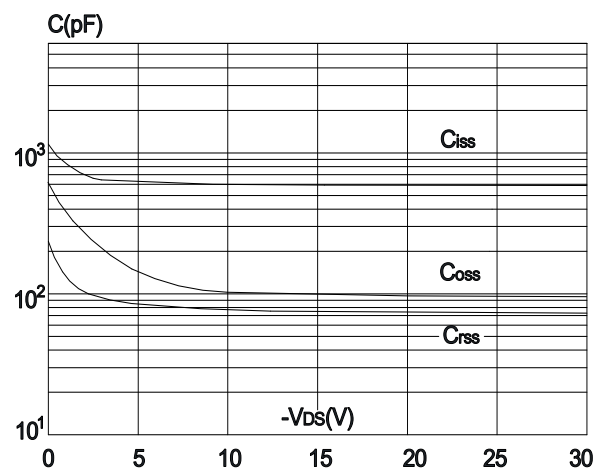


Figure 6: Capacitance Characteristics



Typical Performance Characteristics

Figure 7: Normalized Breakdown Voltage vs. Junction Temperature

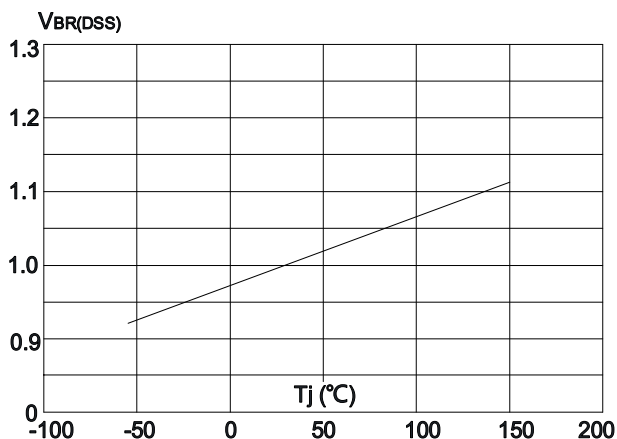


Figure 8: Normalized on Resistance vs. Junction Temperature

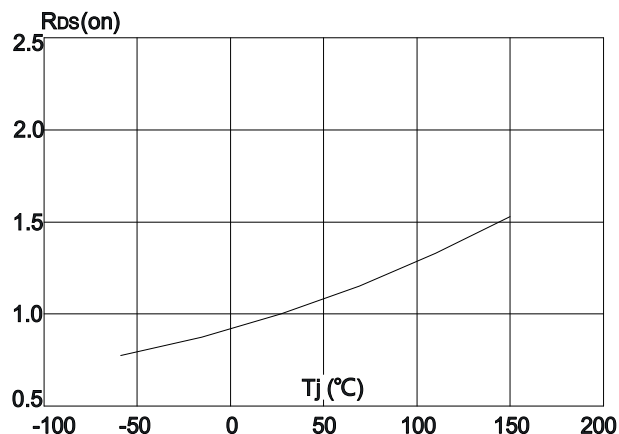


Figure 9: Maximum Safe Operating Area

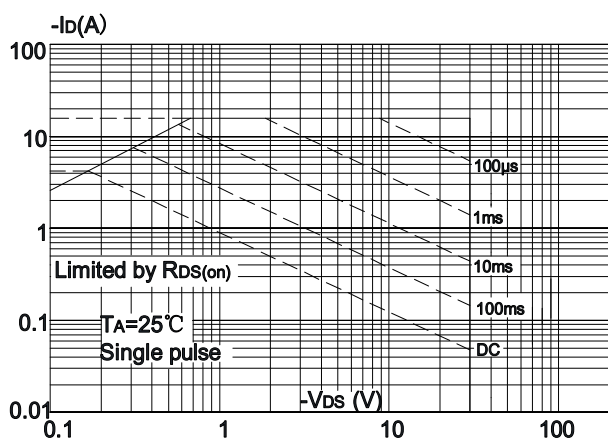


Figure 10: Maximum Continuous Drain Current vs. Ambient Temperature

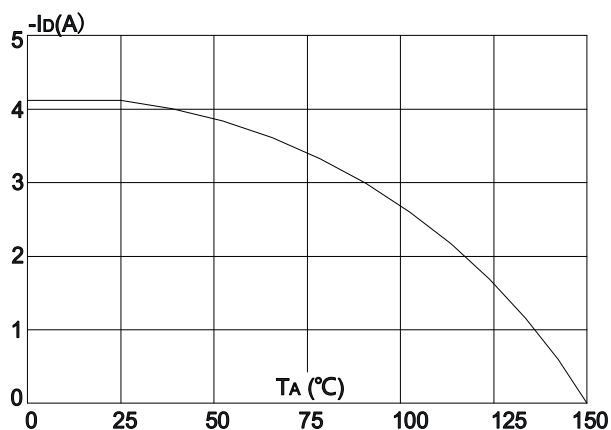
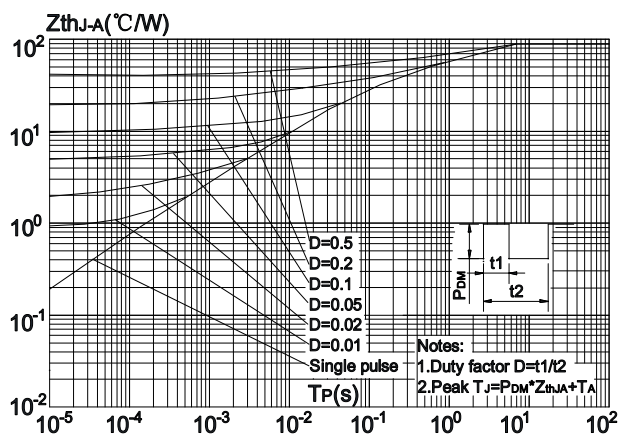
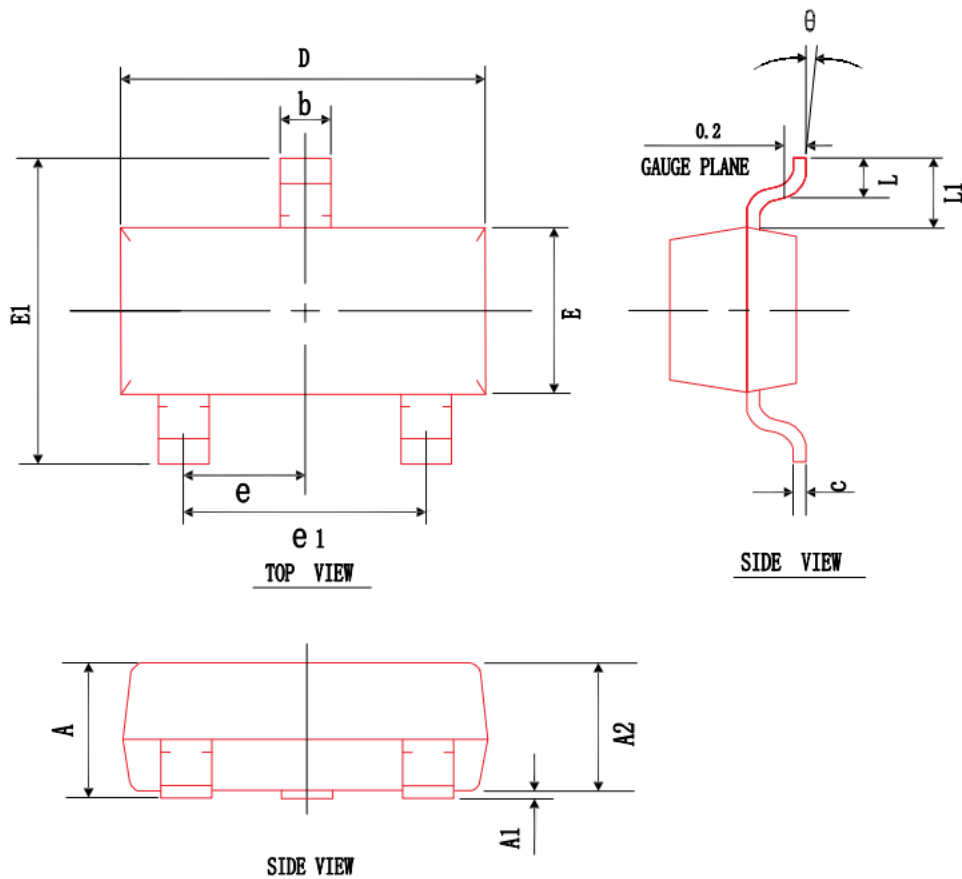


Figure.11: Maximum Effective Transient Thermal Impedance, Junction-to-Ambient



Package Mechanical Data-SOT-23



COMMON DIMENSIONS
(UNITS OF MEASURE=mm)

SYMBOL	MIN	NOM	MAX
A	0.90	1.05	1.30
A1	0.00	0.05	0.10
A2	0.90	1.00	1.20
b	0.30	0.40	0.50
c	0.08	0.10	0.15
D	2.70	2.90	3.10
E	1.20	1.30	1.40
E1	2.20	2.40	2.70
L	0.20	0.40	0.50
θ	0°	5°	10°
L1	0.55 REF		
e	0.95 BSC		
e1	1.90 REF		

Revision History

Revision	Release	Remark
V1.0	2024/05/05	Reset

Disclaimer

The information given in this document describes the independent performance of the product, but similar performance is not guaranteed under other working conditions, and cannot be guaranteed when installed with other products or equipment. To achieve the required performance of the product in actual scenarios, the customer should conduct a complete application test to assess the functionality of the product.

Allpower assumes no responsibility for equipment failures result from using products at values that exceed the ratings, operating conditions, or other parameters listed in the product specifications.

The product described in this specification is not applicable for aerospace or other applications which requires high reliability. Customers using or selling these products for use in medical, life-saving, or life-sustaining applications do so at their own risk and agree to fully indemnify.

Due to product or technical improvements, the information described or contained herein may be changed without prior notice.